

UF200 THRU UF2010

ULTRAFAST SWITCHING RECTIFIER
VOLTAGE - 50 to 1000 Volts
CURRENT - 2.0 Amperes



FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O utilizing Flame Retardant Epoxy Molding Compound
- Void-free Plastic in DO-15 package
- 2.0 ampere operation at $T_A=55\text{ }\text{ }^\circ\text{J}$ with no thermal runaway
- Exceeds environmental standards of MIL-S-19500/228
- Ultra fast switching for high efficiency

MECHANICAL DATA

Case: Molded plastic, DO-15

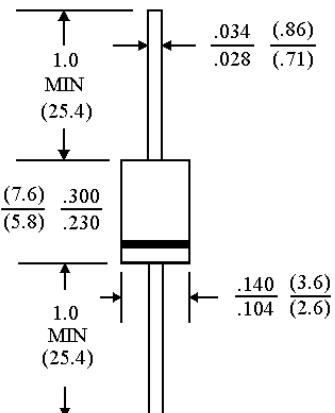
Terminals: Axial leads, solderable per MIL-STD-202,
 Method 208

Polarity: Band denotes cathode

Mounting Position: Any

Weight: 0.015 ounce, 0.4 gram

DO-15



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at $25\text{ }\text{ }^\circ\text{J}$ ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

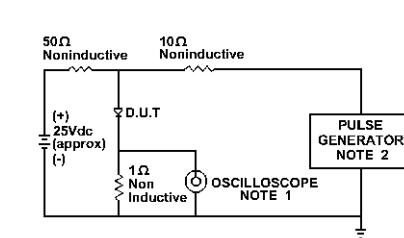
	UF200	UF201	UF202	UF204	UF206	UF208	UF2010	UNITS
Peak Reverse Voltage, Peptitive ; V_{RM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
DC Blocking Voltage; VR	50	100	200	400	600	800	1000	V
Average Forward Current, $I_o @ T_A=55\text{ }\text{ }^\circ\text{J}$ 3.8" lead length, 60Hz, resistive or inductive load					2.0			A
Peak Forward Surge Current I_{FM} (surge) 8.3msec. single half sine-wave superimposed on rated load (JEDEC method)				60				A
Maximum Forward Voltage $V_F @ 2.0A, 25\text{ }^\circ\text{C}$	1.00		1.10		1.70			V
Maximum Reverse Current, @ Rated $T_J=25\text{ }^\circ\text{C}$			10.0					μA
Reverse Voltage $T_J=100\text{ }^\circ\text{C}$			500					μA
Typical Junction capacitance (Note 1) C_J			35					pF
Typical Junction Resistance (Note 2) R_{JKJA}			45					$^\circ\text{C/W}$
Reverse Recovery Time $I_F=.5\text{A}, I_R=1\text{A}, I_{RR}=.25\text{A}$	50	50	50	50	75	75	75	ns
Operating and Storage Temperature Range				-55 TO +150				$\text{ }^\circ\text{J}$

NOTES:

1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC
2. Thermal resistance from junction to ambient and from junction to lead length 0.375"(9.5mm) P.C.B. mounted

RATING AND CHARACTERISTIC CURVES
UF200 THRU UF2010

GM GarboMicro
Semiconductor



NOTE: 1.Rise Time = 7ns max.
Input Impedance = 1 megohm. 22pF
2.Rise Time = 10ns max.
Source Impedance = 50 Ohms

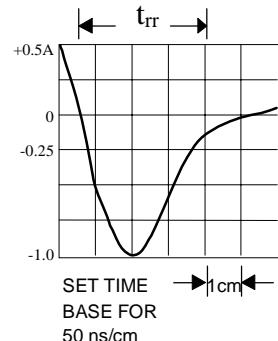


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

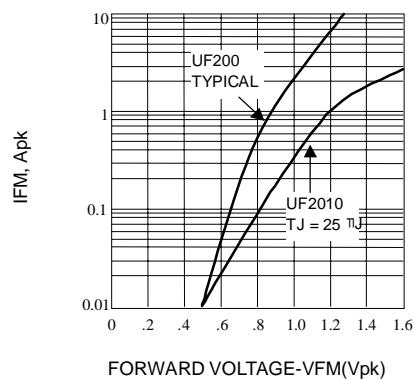


Fig. 2-FORWARD CHARACTERISTICS

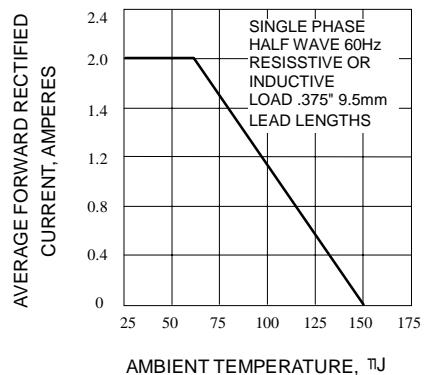


Fig. 3-FORWARD CURRENT DERATING CURVE

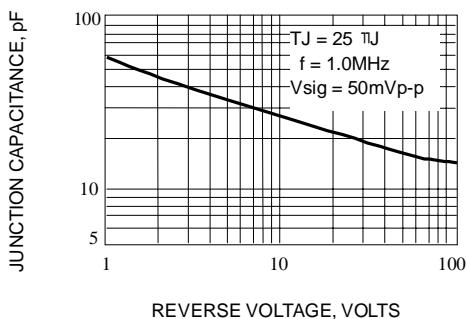


Fig. 4-TYPICAL JUNCTION CAPACITANCE

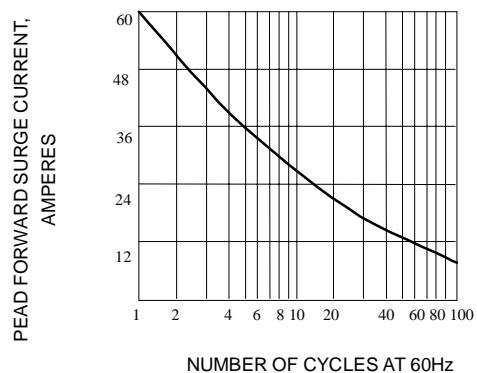


Fig. 5-PEAK FORWARD SURGE CURRENT